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H. Liu, D.C. Bertolet and J.W. Rogers, Jr., Reactions of trimethylaluminium and ammonia on alumina at 600 K – surface chemical aspects of AlN thin film growth 340 (1995) 88

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J. Kühnle and O. Weis, Mechanochemical superpolishing of diamond using $NaNO_3$ or KNO_3 as oxidizing agents 340 (1995) 16

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